I. Power section

Absolute maximum ratings		T_s = 25°C unless otherwise specified	
Symbol	**Conditions**	**Values**	**Units**
IGBT			
V_{CES}		1200	V
V_{CC} [1)]	Operating DC link voltage	900	V
V_{GES}		± 20	V
I_C	T_s = 25 (70) °C	150 (112,5)	A
Inverse diode			
I_F = -I_C	T_s = 25 (70) °C	150 (112,5)	A
I_{FSM}	T_j = 150 °C, t_p = 10ms; sin	1440	A
I^2t (Diode)	Diode, T_j = 150 °C, 10ms	10	kA^2s
T_j , (T_{stg})		-40 (-25) ...+150 (125)	°C
V_{isol}	AC, 1min.	3000	V

Characteristics		T_s = 25°C unless otherwise specified			
Symbol	**Conditions**	**min.**	**typ.**	**max.**	**Units**
IGBT					
V_{CEsat}	I_C = 125A, T_j = 25 (125)°C	–	2,6 (3,1)	3,1	V
V_{CEO}	T_j = 25 (125) °C	–	1,2 (1,3)	1,5 (1,6)	V
r_{CE}	T_j = 25 (125) °C	–	10,5 (14,0)	12,6 (16,1)	mΩ
I_{CES}	V_{GE}=0,V_{CE}=V_{CES},T_j=25(125) °C	–	(10)	0,4	mA
E_{on} + E_{off}	I_C=125A, Vcc=600V	–	–	38	mJ
	T_j=125°C Vcc=900V	–	–	66	mJ
$R_{CC'-EE'}$	terminal chip, T_j = 125 °C	–	0,50	–	mΩ
L_{CE}	top, bottom	–	15,0	–	nH
C_{CHC}	per phase, AC-side	–	1,4	–	nF
Inverse diode					
V_F = V_{EC}	I_F= 150A; T_j = 25(125) °C	–	2,1 (1,9)	2,6	V
V_{TO}	T_j = 25 (125) °C	–	1,3 (1,0)	1,4 (1,1)	V
r_T	T_j = 25 (125) °C	–	5,0 (6,0)	6,8 (7,8)	mΩ
E_{RR}	I_C=125A Vcc=600V	–	–	6	mJ
	T_j=125°C Vcc=900V	–	–	8	mJ
Mechanical data					
M_{dc}	DC terminals, SI Units	6	–	8	Nm
M_{ac}	AC terminals, SI Units	13	–	15	Nm
w	SKiiP® 2 System w/o heat sink	–	1,9	–	kg
w	heat sink	–	4,7	–	kg
Thermal characteristics (P16 heat sink; 310 m^3/ h); "r" reference to temperature sensor					
$R_{thjrIGBT}$	per IGBT	–	–	0,180	K/W
$R_{thjrdiode}$	per diode	–	–	0,375	K/W
R_{thra}	per module	–	–	0,044	K/W

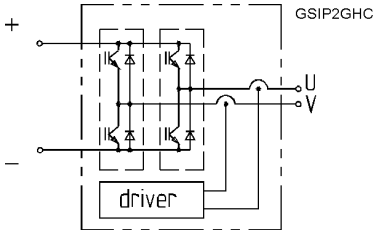
Z_{th}	R_i (mK/W) (max.)				tau$_i$(s)			
	1	2	3	4	1	2	3	4
$IGBT_{jr}$	20	139	22	–	1	0,13	0,001	–
$diode_{jr}$	41	289	45	–	1	0,13	0,001	–
$heatsink_{ra}$	14,2	19,3	6,8	3,7	262	50	5	0,02

SKiiP® 2

SK integrated intelligent Power 4-pack

SKiiP 132GH120-212CTV

Case S2



Features

- SKiiP technology inside
- low loss IGBTs
- CAL diode technology
- integrated current sensor
- integrated temperature sensor
- integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP® 2 System)
- IEC 68T.1 (climate) 40/125/56 (SKiiP® 2 power section)

1) with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)

SKiiP 2®

SK integrated intelligent Power

SKiiP 132GH120-212CTV

II. Integrated gate driver

Absolute maximum ratings

Symbol	Term	Value	Unit
V_{S1}	stabilized 15V power supply	18	V
V_{S2}	unstabilized 24V power supply	30	V
V_{iH}	input signal voltage (high)	15 + 0,3	V
dv/dt	secondary to primary side	75	kV/µs
V_{isolIO}	input / output (AC)	3000	Vac
V_{isol12}	output 1 / output 2 (AC)	1500	Vac
f_{max}	switching frequency	20	kHz
T_{op} (T_{stg})	operating / storage temperature	- 25 ... + 85	°C

Gate driver features

- CMOS compatible inputs
- wide range power supply
- integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- short circuit protection
- over current protection
- over voltage protection (option)
- power supply protected against under voltage
- interlock of top/bottom switch
- isolation by transformers
- fibre optic interface (option for GB-types only)
- IEC 68T.1 (climate) 25/85/56 (SKiiP® 2 gate driver)

Electrical characteristics (T_a = 25 °C)

Symbol	Term		Values min	typ	max.	Units
V_{S1}	supply voltage stabilized		14,4	15	15,6	V
V_{S2}	supply voltage non stabilized		20	24	30	V
I_{S1}	V_{S1} = 15V	230 + 150*f / f_{max} + 1,3* (I_{AC}/A)				mA
I_{S2}	V_{S2} = 24V	170 + 130*f / f_{max} + 1,0 * (I_{AC}/A)				mA
V_{iT+}	input threshold voltage (High)		11,2	–	–	V
V_{iT-}	input threshold voltage (Low)		–	–	5,4	V
R_{in}	input resistance		–	10	–	kΩ
$t_{d(on)IO}$	turn-on propagation time (system)		–	1,2	–	µs
$t_{d(off)IO}$	turn-off propagation time (system)		–	1,6	–	µs
$t_{pERRRESET}$	error memory reset time		9	–	–	µs
t_{TD}	top/bottom switch: interlock time		–	2,3	–	µs
$I_{analogOUT}$	8 V corresponds to		–	150	–	A
$I_{Vs1outmax}$	max. current of 15 V supply voltage (available when supplied with 24V)		–	–	50	mA
I_{AOmax}	output current at pin 15/16/18/19		–	–	5	mA
V_{ol}	logic low output voltage		–	–	0,6	V
V_{oH}	logic high output voltage		–	–	30	V
I_{TRIPSC}	over current trip level ($I_{analog\ OUT}$ = 10V)		–	188	–	A
I_{TRIPLG}	ground fault protection		–	43	–	A
T_{tp}	over temperature protection		110	–	120	°C
U_{DCTRIP}	trip level of U_{DC}-protection ($U_{analog\ OUT}$ = 9V); (option)		900	–	–	V

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